

## KSD794/794A

# Audio Frequency Power Amplifier • Complement to KSB744/KSB744A



## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter		Value	Units
V <sub>CBO</sub>	Collector- Base Voltage		70	V
V <sub>CEO</sub>	Collector-Emitter Voltage	: KSD794	45	V
		: KSD794A	60	V
$V_{EBO}$	Emitter- Base Voltage		5	V
I <sub>C</sub>	Collector Current (DC)		3	Α
I <sub>CP</sub>	*Collector Current (Pulse)		5	Α
$I_{B}$	Base Current (DC)		0.6	Α
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)		1	W
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)		10	W
T <sub>J</sub>	Junction Temperature		150	°C
T <sub>STG</sub>	Storage Temperature		- 55 ~ 150	°C

<sup>\*</sup> PW≤10ms, Duty Cycle≤50%

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 45V, I_{E} = 0$			1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 3V, I_{C} = 0$			1	μΑ
h <sub>FE1</sub>	* DC Current Gain	$V_{CE} = 5V, I_{C} = 20mA$	30	70		
$h_{FE2}$		$V_{CE} = 5V, I_{C} = 0.5A$	60	100	320	
V <sub>CE</sub> (Sat)	* Collector-Emitter Saturation Voltage	$I_C = 1.5A, I_B = 0.15A$		0.3	2	V
V <sub>BE</sub> (Sat)	* Base-Emitter Saturation Voltage	$I_C = 1.5A, I_B = 0.15A$		0.8	2	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{E} = 0.1A$		60		MHz
C <sub>ob</sub>	Output Capacitance	$V_{CB} = 10V, I_{E} = 0, f = 1MHz$		40		pF

<sup>\*</sup> Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

## **h**<sub>FE</sub> Classificntion

Classification	R	0	Y
h <sub>FE2</sub>	60 ~ 120	100 ~ 200	160 ~ 320

## **Typical Characteristics**

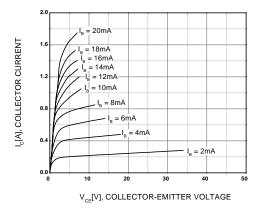


Figure 1. Static Characteristic

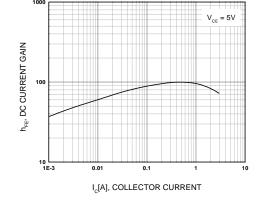


Figure 2. DC current Gain

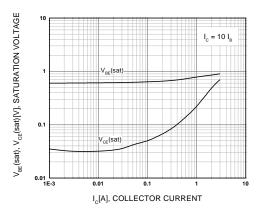


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

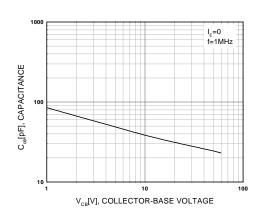


Figure 4. Collector Output Capacitance

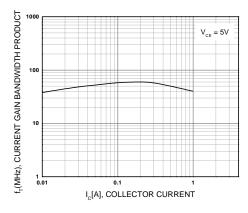


Figure 5. Current Gain Bandwidth Product

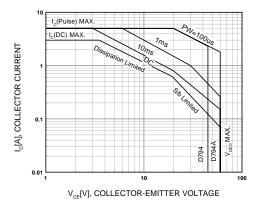
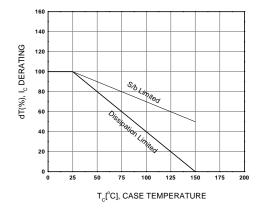


Figure 6. Safe Operating Area

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# Typical Characteristics (Continued)





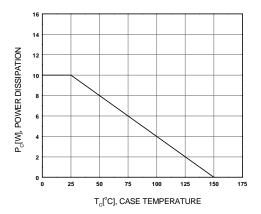
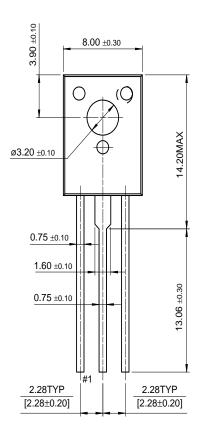
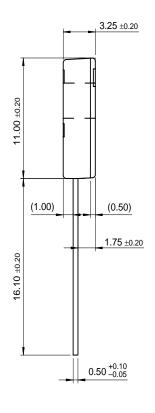


Figure 8. Power Derating

# **Package Demensions**

TO-126







Dimensions in Millimeters

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